

MAGX-100027-300C0P

Rev. V2

Features

- Suitable for Linear and Saturated Applications
- Pair of Isolated, Symmetric Amplifiers
- CW and Pulsed Operation: 300 W Output Power
- Internally Pre-Matched
- 260°C Reflow Compatible
- 50 V Operation
- 100% RF Tested
- RoHS* Compliant

Description

The MAGX-100027-300C0P is high power GaN on Si HEMT device optimized for DC - 2.7 GHz frequency operation. The device supports both CW and pulsed operation with peak output power levels of 300 W (54.8 dBm) in a plastic package.

The MAGX-100027-300C0P is ideally suited for a multitude of applications including military radio communications, digital cellular infrastructure, RF energy, avionics, test instrumentation and RADAR.

Typical Performance:

• $V_{DS} = 50 \text{ V}, I_{DQ} = 100 \text{ mA}, T_C = 25^{\circ}\text{C}$. One side Measured under pulsed load-pull at 2.5 dB Compression, 100 µs pulse width,1 ms period, 10% duty cycle

Frequency (GHz)	Output Power ¹ (dBm)	Gain ² (dB)	η ₀ ² (%)
0.9	53.5	20.0	71.1
1.4	53.3	17.6	74.8
2.0	53.5	15.0	64.3
2.5	53.5	13.5	64.8
2.7	53.4	13.5	65.3

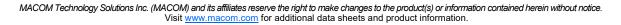
1. Load impedance tuned for maximum output power.

Load impedance tuned for maximum drain efficiency.

Ordering Information

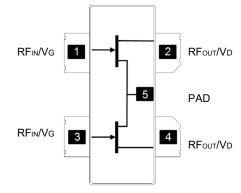
Part Number	Package
MAGX-100027-300C0P	Bulk quantity
MAGX-100027-300CTP	Tape and Reel
MAGX-1A0027-300C0P	Sample board

* Restrictions on Hazardous Substances, compliant to current RoHS EU directive.





Functional Schematic



Pin Configuration

Pin #	Pin Name	Function
1	RF _{IN} / V _{G1}	RF Input / Gate
2	RF _{OUT} / V _{D1}	RF Output / Drain
3	$\mathrm{RF}_{\mathrm{IN}}$ / V_{G2}	RF Input / Gate
4	$\mathrm{RF}_{\mathrm{OUT}}$ / V_{D2}	RF Output / Drain
5	Pad ³	Ground / Source

3. The exposed pad centered on the package bottom must be connected to RF, DC and thermal ground.



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RF Electrical Characteristics: $T_c = 25^{\circ}C$, $V_{DS} = 50 V$, $I_{DQ} = 200 mA$ Note: Performance in MACOM Evaluation Test Fixture, 50 Ω system

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
Small Signal Gain	Pulsed ⁴ , 2 GHz	G _{SS}	-	16.3	-	dB
Power Gain	Pulsed ⁴ , 2 GHz, 2.5 dB Gain Compression	G _{SAT}	-	14.0	-	dBm
Saturated Drain Efficiency	Pulsed ⁴ , 2 GHz, 2.5 dB Gain Compression	η_{SAT}	-	57.5	-	%
Saturated Output Power	Pulsed ⁴ , 2 GHz, 2.5 dB Gain Compression	P _{SAT}	-	55.5	-	dBm
Gain Variation (-25°C to +85°C)	Pulsed ⁴ , 2 GHz	ΔG	-	0.02	-	dB/∘C
Power Variation (-25°C to +85°C)	Pulsed ⁴ , 2 GHz	$\Delta P2.5 dB$	-	0.01	-	dB/∘C
Gain	Pulsed ⁴ , 2 GHz, P _{IN} = 41.2 dBm	G _P	-	14.5	-	dB
Drain Efficiency	Pulsed ⁴ , 2.0 GHz, P _{IN} = 41.2 dBm	η	-	57.5	-	%
Ruggedness: Output Mismatch	All phase angles	Ψ VSWR = 10:1, No E		l, No Da	mage	

RF Electrical Specifications: $T_A = 25^{\circ}C$, $V_{DS} = 50$ V, $I_{DQ} = 200$ mA Note: Performance in MACOM Production Test Fixture, 50 Ω system

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
Power Gain	Pulsed ⁴ , 2 GHz, 2.5 dB Gain Compression	G _{SAT}	13	14	-	dB
Saturated Drain Efficiency	Pulsed ⁴ , 2 GHz, 2.5 dB Gain Compression	η_{SAT}	52	57.5	-	%
Saturated Output Power	Pulsed ⁴ , 2 GHz, 2.5 dB Gain Compression	P _{SAT}	54	55.4	-	dBm
Gain	Pulsed ⁴ , 2 GHz, P_{IN} = 41.2 dBm	G _P	13	14.2	-	dB
Drain Efficiency	Pulsed ⁴ , 2 GHz, P_{IN} = 41.2 dBm	η	52	57.5	-	dB

4. Pulse details: 100 µs pulse width, 1 ms period, 10% Duty Cycle.

DC Electrical Characteristics (Per Each Side of Symmetric Device) T_A = 25°C

Parameter	Test Conditions	Symbol	Min.	Тур.	Max.	Units
Drain-Source Leakage Current	V _{GS} = -8 V, V _{DS} = 130 V		-	-	29.2	mA
Gate-Source Leakage Current	V_{GS} = -8 V, V_{DS} = 0 V	I _{GLK}	-	-	29.2	mA
Gate Threshold Voltage	V _{DS} = 50 V, I _D = 29.2 mA	VT	-2.6	-2.15	-1.6	V
Gate Quiescent Voltage	V _{DS} = 50 V, I _D = 150 mA	V_{GSQ}	-2.4	-2.05	-1.4	V
On Resistance	V _{GS} = 2 V, I _D = 200 mA	R _{ON}	-	0.16	-	Ω
Maximum Drain Current	V_{DS} = 7 V pulsed, pulse width 300 µs	I _{D, MAX}	-	17.0	-	Α

²

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Absolute Maximum Ratings (Per Each Side of Symmetric Device)^{5,6,7,8,9}

Parameter	Absolute Maximum
Drain Source Voltage, V _{DS}	130 V
Gate Source Voltage, V _{GS}	-10 to 3 V
Gate Current, I _G	29 mA
Storage Temperature Range	-65°C to +150°C
Case Operating Temperature Range	-40°C to +85°C
Channel Operating Temperature Range, T _{CH}	-40°C to +225°C
Absolute Maximum Channel Temperature	+250°C

5. Exceeding any one or combination of these limits may cause permanent damage to this device.

MACOM does not recommend sustained operation above maximum operating conditions. 6.

7.

8.

Operating at drain source voltage $V_{DS} < 55$ V will ensure MTTF > 1 x 10⁷ hours. Operating at nominal conditions with $T_{CH} \le 225^{\circ}$ C will ensure MTTF > 1 x 10⁷ hours. MTTF may be estimated by the expression MTTF (hours) = A $e^{[B + C/(T+273)]}$ where *T* is the channel temperature in degrees Celsius, 9 A = 3.686, B = -35.00, and C = 25,416.

Thermal Characteristics¹⁰

Parameter	Test Conditions	Symbol	Typical	Units
Thermal Resistance using Finite Element Analysis	V _{DS} = 50 V, T _C = 85°C, T _{CH} = 225°C	$R_{\theta}(FEA)$	0.56	°C/W
Thermal Resistance using Infrared Measurement of Die Surface Temperature	V _{DS} = 50 V, T _C = 85°C, T _{CH} = 225°C	R _θ (IR)	0.45	°C/W

10. Case temperature measured using thermocouple embedded in heat-sink. Contact local applications support team for more details on this measurement.

Handling Procedures

Please observe the following precautions to avoid damage:

Static Sensitivity

Gallium Nitride Circuits are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these HBM Class 1A, CDM Class C3 devices.

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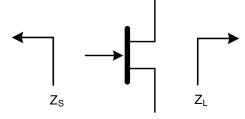


Pulsed⁴ Load-Pull Performance (Per Each Side of Symmetric Device) Reference Plane at Device Leads

		Maximum Output Power							
			V _{DS} = 50 V, I _{DQ} = 100 mA, T _C = 25°C, P2.5dB						
Frequency (GHz)	Z _{SOURCE} (Ω)	Z _{LOAD} ¹¹ (Ω)	Gain (dB)	Р _{оит} (dBm)	Р _{оит} (W)	η₀ (%)	AM/PM ¹³ (°)		
0.9	5 - j2.0	3.4 - j0.4	19.3	53.5	222.6	58.3	0.3		
1.4	5 - j4.6	2.6 - j0.7	16.0	53.3	215.6	62.7	0.5		
2.0	5 - j6.3	1.8 - j1.8	14.4	53.5	222.6	61.3	-3.4		
2.5	5 - j11.0	1.5 - j3.2	12.9	53.5	222.6	60.6	-6.4		
2.7	5 - j11.0	1.9 - j3.8	12.3	53.4	220.9	59.0	-9.6		

		Maximum Drain Efficiency						
		V _{DS} = 50 V, I _{DQ} = 100 mA, T _C = 25°C, P2.5dB						
Frequency (GHz)	Z _{SOURCE} (Ω)	Z _{LOAD} ¹² (Ω)	Gain (dB)	Р _{оит} (dBm)	Р _{оит} (W)	η₀ (%)	AM/PM ¹³ (°)	
0.9	5 - j2.0	5.4 + j3.0	20.0	52.4	175.5	71.1	-4.8	
1.4	5 - j4.6	2.5 + j1.6	17.6	51.9	154.6	74.8	-3.5	
2.0	5 - j6.3	1.8 - j1.1	15.0	52.9	195.2	64.3	-3.8	
2.5	5 - j11.0	1.4 - j2.3	13.5	52.6	180.0	64.8	-8.5	
2.7	5 - j11.0	1.1 - j2.7	13.5	51.8	148.5	65.3	-17.0	

Impedance Reference



 Z_{SOURCE} = Measured impedance presented to the input of the device at package reference plane. Z_{LOAD} = Measured impedance presented to the output of the

device at package reference plane.

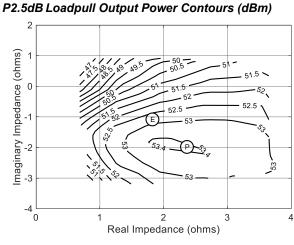
- 11. Load Impedance for optimum output power.
- 12. Load Impedance for optimum efficiency.
- 13. AM/PM are relative values.

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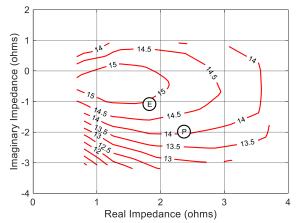


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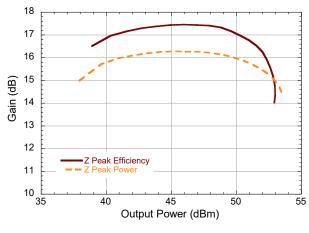
Pulsed⁴ Load-Pull Performance (Per Each Side of Symmetric Device) 2.0 GHz



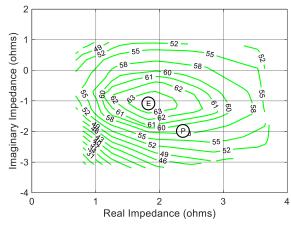
P2.5dB Loadpull Gain Contours (dB)



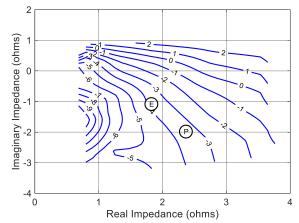
Gain vs. Output Power



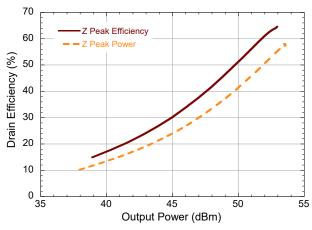
P2.5dB Loadpull Drain Efficiency Contours (%)



P2.5dB Loadpull AM/PM Contours (°)



Drain Efficiency vs. Output Power

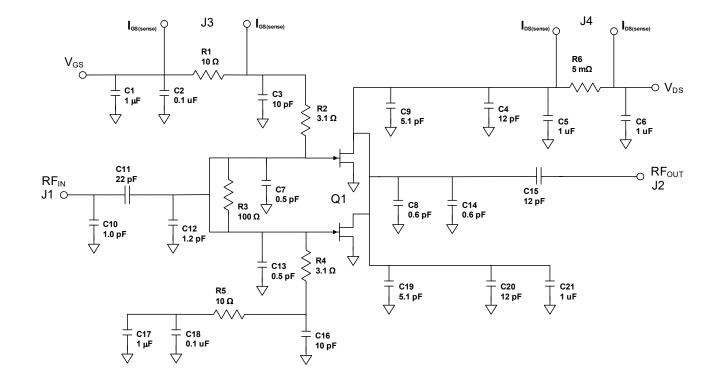


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Evaluation Test Fixture and Recommended Tuning Solution 1.95 - 2.05 GHz

Description

Parts measured on evaluation board (20-mil thick RO4350). Matching is provided using a combination of lumped elements and transmission lines as shown in the simplified schematic above. Recommended tuning solution component placement, transmission lines, and details are shown on the next page.

Bias Sequencing Turning the device ON

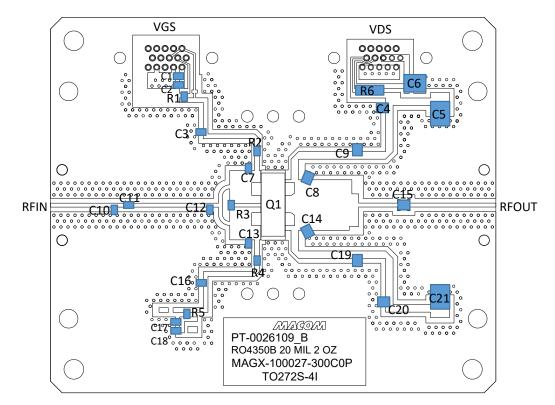
- 1. Set V_{GS} to pinch-off (V_P).
- 2. Turn on V_{DS} to nominal voltage (50 V).
- 3. Increase V_{GS} until I_{DS} current is reached.
- 4. Apply RF power to desired level.

Turning the device OFF

- 1. Turn the RF power off.
- 2. Decrease V_{GS} down to V_P pinch-off.
- 3. Decrease V_{DS} down to 0 V.
- 4. Turn off V_{GS} .

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Evaluation Test Fixture and Recommended Tuning Solution 1.95 - 2.05 GHz

Reference Designator	Value	Tolerance	Manufacturer	Part Number	
C1, C18	1.0 µF	+/- 10 %	Murata	GRM21BC72A105KE01L	
C2, C17	0.1 µF	+/- 10 %	Murata	GCD21BR72A104KA01L	
C3, C16	10 pF	+/- 0.1 pF	PPI	0505C100BW151X	
C4, C15, C20	12 pF	+/- 0.1 pF	PPI	111N120BW501X	
C5, C6, C21	1 µF	+/- 10 %	Murata	GRM55DR72E105KW01L	
C7, C13	0.5 pF	+/- 0.1 pF	PPI	0505C0R5BW151X	
C8, C14	0.6 pF	+/- 0.1 pF	PPI	1111N0R6BW501X	
C9, C19	5.1 pF	+/- 0.1 pF	PPI	1111N5R1BW501X	
C10	1 pF	+/- 0.1 pF	PPI	0505C1R0BW151X	
C11	22 pF	+/- 0.1 pF	PPI	0505C220JW151X	
C12	1.2 pF	+/- 0.1 pF	PPI	0505C1R2BW151X	
R1, R5	10 Ω	+/- 1 %	Vishay Dale	CRCW080510R0FKTA	
R2, R4	3.1 Ω	+/- 1 %	Vishay Dale	CRCW08053R09FKEA	
R3	100 Ω	+/- 1 %	Vishay Dale	CRCW0805100RFKEA	
R6	5 mΩ	+/- 1 %	Susumu	RL7520WT-R005-F	
Q1	MACO	COM GaN Power Amplifier MAGX-100027-300C0P			
PCB		RO4350,	20 mil, 2 oz. Cu, A	u Finish	

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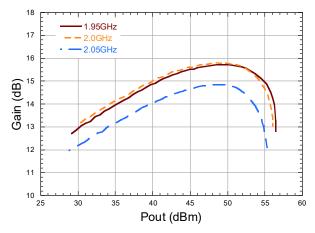


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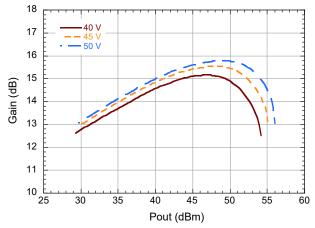
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Typical Performance Curves as Measured in the 1.95 - 2.05 GHz Evaluation Test Fixture: Pulsed⁴ 2.0 GHz, V_{DS} = 50 V, I_{DQ} = 200 mA, T_{C} = 25°C (Unless Otherwise Noted)

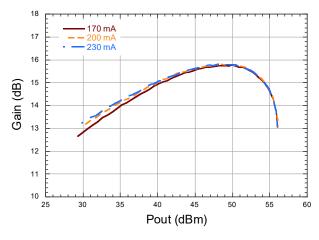
Gain vs. Output Power and Frequency



Gain vs. Output Power and V_{DS}

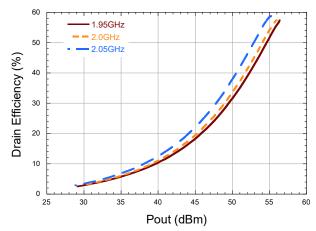


Gain vs. Output Power and IDQ

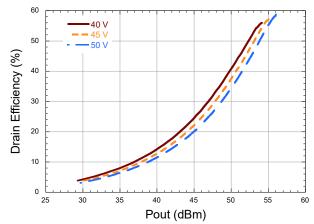


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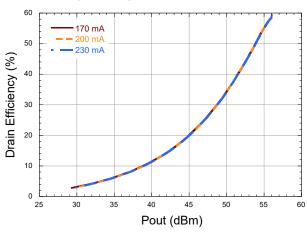
Drain Efficiency vs. Output Power and Frequency



Drain Efficiency vs. Output Power and V_{DS}



Drain Efficiency vs. Output Power and IDQ



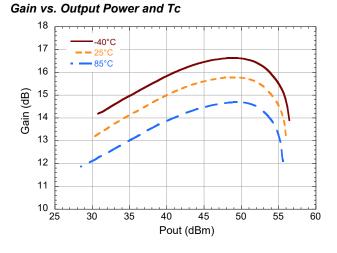
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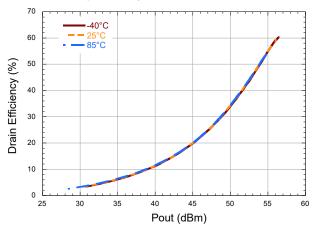
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Typical Performance Curves as Measured in the 1.95 - 2.05 GHz Evaluation Test Fixture: $Pulsed^4 2.0 GHz$, $V_{DS} = 50 V$, $I_{DQ} = 200 mA$, $T_C = 25^{\circ}C$ (Unless Otherwise Noted)



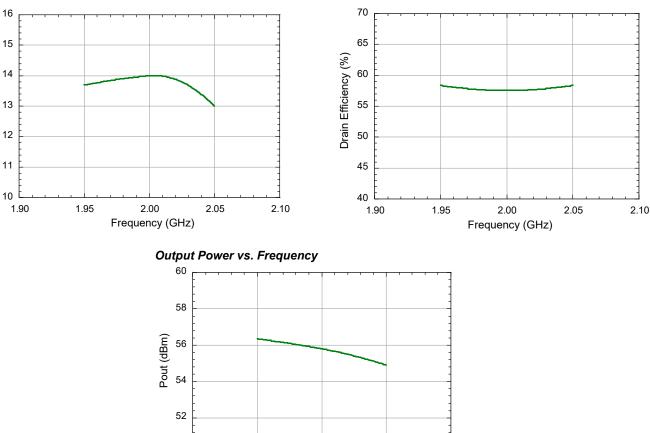
Drain Efficiency vs. Output Power and Tc



Gain vs. Frequency

Gain (dB)

Drain Efficiency vs. Frequency



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2.00 Frequency (GHz) 2.05

2.10

1.95

50

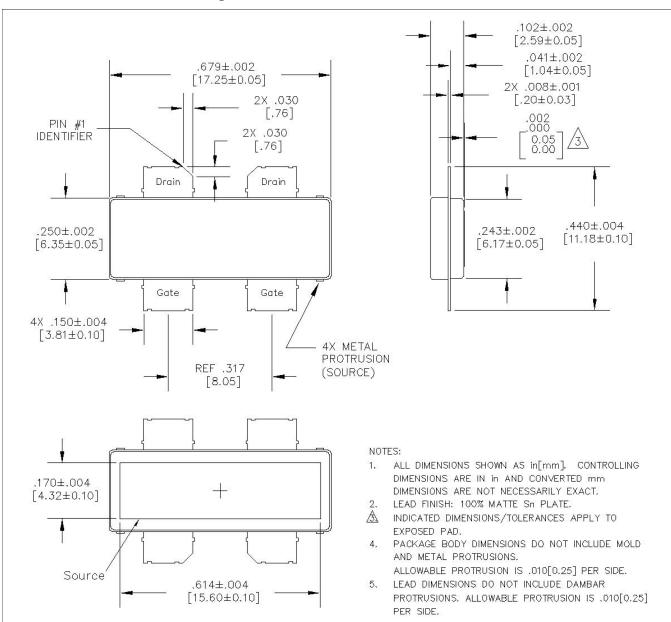
1.90

⁹



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Lead-Free TO-272S-4I Package Dimensions[†]

[†] Reference Application Note AN0004125 for lead-free solder reflow recommendations. Meets JEDEC moisture sensitivity level 3 requirements. Plating is Matte Sn.

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